

## HIGH SPEED 2K X 16 DUAL-PORT SRAM

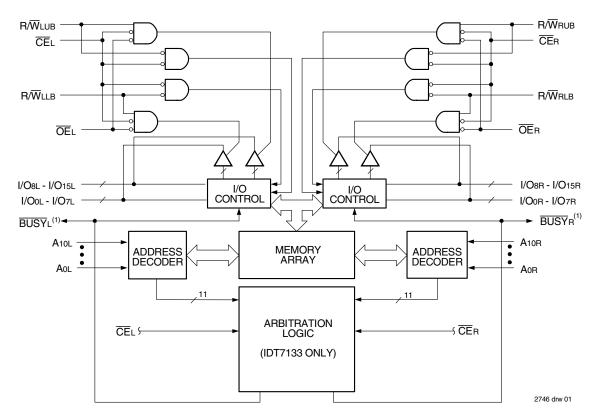
7133SA/LA 7143SA/LA

## Features

#### High-speed access

- Commercial: 20/25/35/45/55/70/90ns (max.)
- Industrial: 25ns (max.)
- Military: 35/55/70/90ns (max.)
- Low-power operation
  - IDT7133/43SA
    Active: 1150mW (typ.)
    Standby: 5mW (typ.)
  - IDT7133/43LA
    Active: 1050mW (typ.)
    Standby: 1mW (typ.)
- Versatile control for write: separate write control for lower and upper byte of each port
- Functional Block Diagram

- MASTER IDT7133 easily expands data bus width to 32 bits or more using SLAVE IDT7143
- On-chip port arbitration logic (IDT7133 only)
- BUSY output flag on IDT7133; BUSY input on IDT7143
- Fully asynchronous operation from either port
- Battery backup operation-2V data retention
- TTL-compatible; single 5V (±10%) power supply
- Available in 68-pin ceramic PGA, Flatpack, PLCC and 100pin TQFP
- Military product compliant to MIL-PRF-38535 QML
- Industrial temperature range (-40°C to +85°C) is available for selected speeds
- Green parts available, see ordering information



#### NOTE:

 IDT7133 (MASTER): <u>BUSY</u> is open drain output and requires pull-up resistor. IDT7143 (SLAVE): <u>BUSY</u> is input.

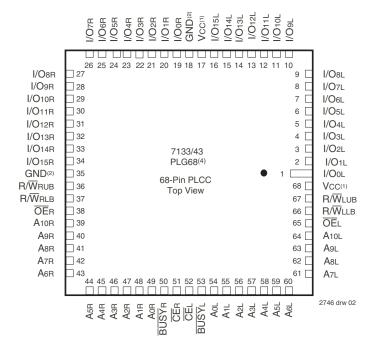


#### Military, Industrial and Commercial Temperature Ranges

### Description

The IDT7133/7143 are high-speed 2K x 16 Dual-Port Static RAMs. The IDT7133 is designed to be used as a stand-alone 16-bit Dual-Port RAM or as a "MASTER" Dual-Port RAM together with the IDT7143 "SLAVE" Dual-Port in 32-bit-or-more word width systems. Using the IDT MASTER/SLAVE Dual-Port RAM approach in 32-bit-or-wider memory system applications results in full-speed, error-free operation without the need for additional discrete logic.

Both devices provide two independent ports with separate control,



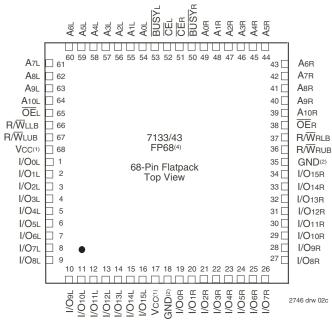
## PinConfigurations<sup>(1,2,3,4)</sup>

address, and I/O pins that permit independent, asynchronous access for reads or writes to any location in memory. An automatic power down feature, controlled by  $\overline{CE}$ , permits the on-chip circuitry of each port to enter a very low standby power mode.

Fabricated using CMOS high-performance technology. Low-power (LA) versions offer battery backup data retention capability, with each port typically consuming 200µW for a 2V battery.

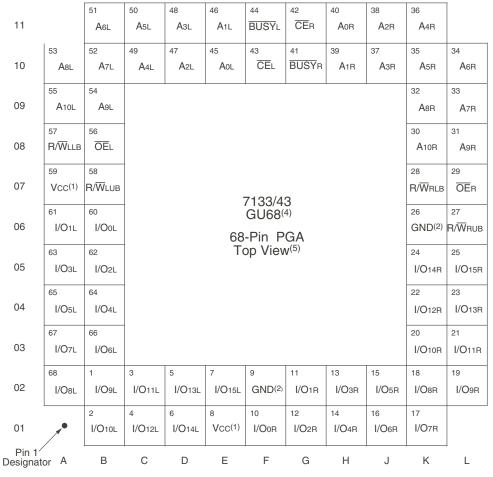
The IDT7133/7143 devices have identical pinouts. Each is packed in a 68-pin ceramic PGA, 68-pin flatpack, 68-pin PLCC and 100-pin TQFP. Military grade product is manufactured in compliance with the latest revision of MIL-PRF-38535 QML, making it ideally suited to military temperature applications demanding the highest level of performance and reliability.

- 1. Both Vcc pins must be connected to the power supply to ensure reliable operation.
- 2. Both GND pins must be connected to the ground supply to ensure reliable operation.
- 3. PLG68 package body is approximately 0.95 in x 0.95 in x 0.17 in. FP68 package body is approximately 1.18 in x 1.18 in x 0.16 in.
- 4. This package code is used to reference the package diagram.





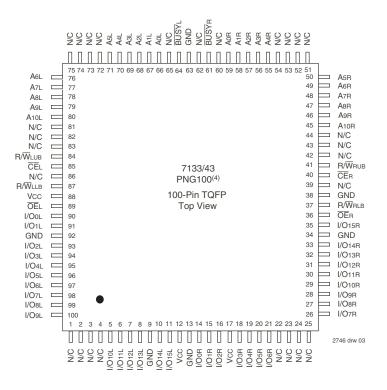
## Pin Configurations<sup>(1,2,3,4)</sup> (con't.)



2746 drw 04

- 1. Both Vcc pins must be connected to the power supply to ensure reliable operation.
- 2. Both GND pins must be connected to the ground supply to ensure reliable operation.
- 3. GU68 package body is approximately 1.18 in x 1.18 in x 0.16 in.
- 4. This package code is used to reference the package diagram.
- 5. This text does not indicate orientation of the actual part-marking.

## Pin Configurations<sup>(1,2,3,4)</sup> (con't.)



#### NOTES:

- Both Vcc pins must be connected to the power supply to ensure reliable operation.
- 2. Both GND pins must be connected to the ground supply to ensure reliable operation.
- 3. PNG100 package body is approximately 14mm x 14mm x 1.4mm.
- 4. This package code is used to reference the package diagram.

## **Pin Names**

| Left Port      | Right Port      | Names                        |  |  |
|----------------|-----------------|------------------------------|--|--|
| <u>CE</u> L    | Ē               | Chip Enable                  |  |  |
| R/Wlub         | R/WRUB          | Upper Byte Read/Write Enable |  |  |
| R/WLLB         | R/Wrlb          | Lower Byte Read/Write Enable |  |  |
| OEL            | <del>0E</del> r | Output Enable                |  |  |
| Aol - A10l     | Aor - A10r      | Address                      |  |  |
| I/O0L - I/O15L | I/O0r - I/O15r  | Data Input/Output            |  |  |
| BUSYL          | BUSYR           | Busy Flag                    |  |  |
| Vcc            |                 | Power                        |  |  |
| G              | ND              | Ground                       |  |  |

2746 tbl 01



Military, Industrial and Commercial Temperature Ranges

## Absolute Maximum Ratings<sup>(1)</sup>

| Symbol               | Rating                                     | Commercial<br>& Industrial | Military     | Unit |
|----------------------|--|----------------------------|--------------|------|
| Vterm <sup>(2)</sup> | Terminal Voltage<br>with Respect<br>to GND | -0.5 to +7.0               | -0.5 to +7.0 | V    |
| Tbias                | Temperature<br>Under Bias                  | -55 to +125                | -65 to +135  | ٥C   |
| Tstg                 | Storage<br>Temperature                     | -65 to +150                | -65 to +150  | ٥C   |
| Ρτ                   | Power<br>Dissipation                       | 2.0                        | 2.0          | W    |
| Ιουτ                 | DC Output<br>Current                       | 50                         | 50           | mA   |

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. VTERM must not exceed Vcc + 10% for more than 25% of the cycle time or 10ns maximum, and is limited to  $\leq$  20mA for the period of VTERM  $\geq$  Vcc + 10%.

## Capacitance (TA = +25°C, f = 1.0mhz)

| Symbol | Parameter <sup>(1)</sup> | Conditions <sup>(2)</sup> | Мах. | Unit        |
|--------|--------------------------|---------------------------|------|-------------|
| Cin    | Input Capacitance        | Vin = 3dV                 | 11   | pF          |
| Соит   | Output Capacitance       | Vout = 3dV                | 11   | pF          |
|        |                          |                           |      | 2746 tbl 03 |

NOTES:

1. This parameter is determined by device characterization but is not production tested.

 3dV references the interpolated capacitance when the input and output switch from 0V to 3V or from 3V to 0V.

## Maximum Operating Temperature and Supply Voltage<sup>(1,2)</sup>

| Grade      | Ambient<br>Temperature | GND | Vcc               |
|------------|------------------------|-----|-------------------|
| Military   | -55°C to +125°C        | 0V  | 5.0V <u>+</u> 10% |
| Commercial | 0°C to +70°C           | 0V  | 5.0V <u>+</u> 10% |
| Industrial | -40°C to +85°C         | 0V  | 5.0V <u>+</u> 10% |

NOTES:

2746 tbl 02

1. This is the parameter TA. This is the "instant on" case temperature.

# Recommended DC Operating Conditions

| Symbol | Parameter          | Min.                | Тур. | Max.               | Unit |  |  |  |  |
|--------|--------------------|---------------------|------|--------------------|------|--|--|--|--|
| Vcc    | Supply Voltage     | 4.5                 | 5.0  | 5.5                | V    |  |  |  |  |
| GND    | Ground             | 0                   | 0    | 0                  | V    |  |  |  |  |
| Vih    | Input High Voltage | 2.2                 |      | 6.0 <sup>(2)</sup> | V    |  |  |  |  |
| VIL    | Input Low Voltage  | -0.5 <sup>(1)</sup> |      | 0.8                | V    |  |  |  |  |
|        | 2746 tbl 05        |                     |      |                    |      |  |  |  |  |

#### NOTES:

1. VIL (min.) = -1.5V for pulse width less than 10ns.

2. VTERM must not exceed Vcc + 10%.

## DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range (Either port, Vcc = 5.0V ± 10%)

|        |   |   | 7133SA<br>7143SA |      | 7133LA<br>7143LA |      |      |
|--------|---|---|------------------|------|------------------|------|------|
| Symbol | Parameter                                       | Test Conditions                         | Min.             | Max. | Min.             | Мах. | Unit |
| lu     | Input Leakage Current <sup>(1)</sup>            | Vcc = 5.5V, VIN = 0V to Vcc             |                  | 10   |                  | 5    | μA   |
| llo    | Output Leakage Current                          | $\overline{CE}$ = VIH, VOUT = 0V to VCC |                  | 10   |                  | 5    | μA   |
| Vol    | Output Low Voltage (I/Oo-I/O15)                 | Iol = 4mA                               |                  | 0.4  |                  | 0.4  | V    |
| Vol    | <u>Open D</u> rain Output Low Voltage<br>(BUSY) | Iol = 16mA                              |                  | 0.5  |                  | 0.5  | V    |
| Vон    | Output High Voltage                             | Ioh = -4mA                              | 2.4              | -    | 2.4              | _    | V    |

#### NOTE:

1. At Vcc  $\leq$  2.0V, input leakages are undefined.

2746 tbl 06

2746 tbl 04



## DC Electrical Characteristics Operating Temperature and Supply Voltage Range<sup>(2)</sup> ( $Vcc = 5.0V \pm 10\%$ )

|        |   |   |              |        |                     |            | 7133<br>7143<br>Com'l | X20        | 7133<br>7143<br>Com'l | X25        | 7133<br>7143<br>Cor<br>& Mill | X35<br>n'l |  |
|--------|---|---|--------------|--------|---------------------|------------|-----------------------|------------|-----------------------|------------|-------------------------------|------------|--|
| Symbol | Parameter   | Test Condition  | Versi        | on     | Typ. <sup>(1)</sup> | Max.       | Typ. <sup>(1)</sup>   | Max.       | Typ. <sup>(1)</sup>   | Мах.       | Unit                          |            |  |
| ICC    | Dynamic Operating<br>Current<br>(Both Ports Active)         | $\overline{CE} = VIL$ , Outputs Disabled<br>f = fMAX <sup>(3)</sup>   | COM'L        | S<br>L | 250<br>230          | 310<br>280 | 250<br>230            | 300<br>270 | 240<br>210            | 295<br>250 | mA                            |            |  |
|        | (DUIT POILS ACTIVE)   | I = IMAX**  | MIL &<br>IND | S<br>L |                     |            | 250<br>230            | 330<br>300 | 240<br>220            | 325<br>295 |                               |            |  |
| ISB1   | Standby Current<br>(Both Ports - TTL                        | $\overline{CEL}$ and $\overline{CER} = VIH$   | COM'L        | S<br>L | 25<br>25            | 80<br>70   | 25<br>25              | 80<br>70   | 25<br>25              | 70<br>60   | mA                            |            |  |
|        | Level Inputs)   | $f = fMAX^{(3)}$  | MIL &<br>IND | S<br>L |                     |            | 25<br>25              | 90<br>80   | 25<br>25              | 75<br>65   |                               |            |  |
| ISB2   | Standby Current<br>(One Port - TTL                          | $\overline{CE}^*A^* = VIL \text{ and } \overline{CE}^*B^* = VIH^{(4)}$<br>f=fMAX <sup>(3)</sup>   | COM'L        | S<br>L | 140<br>120          | 200<br>180 | 140<br>100            | 200<br>170 | 120<br>100            | 180<br>160 | mA                            |            |  |
|        | Level Inputs)   | Active Port Outputs Disabled  | MIL &<br>IND | S<br>L |                     |            | 140<br>100            | 230<br>190 | 120<br>100            | 200<br>180 |                               |            |  |
| ISB3   | Full Standby Current<br>(Both Ports -<br>CMOS Level Inputs) | Both Ports CEL and<br>CER > Vcc - 0.2V<br>VIN > Vcc - 0.2V or   | COM'L        | S<br>L | 1.0<br>0.2          | 15<br>5    | 1.0<br>0.2            | 15<br>4    | 1.0<br>0.2            | 15<br>4    | mA                            |            |  |
|        | CIVIOS Level Inpuis)  | VIN > VCC - 0.2V OI<br>$VIN < 0.2V, f = 0^{(4)}$  | MIL &<br>IND | S<br>L |                     |            | 1.0<br>0.2            | 30<br>10   | 1.0<br>0.2            | 30<br>10   |                               |            |  |
| ISB4   | Full Standby Current<br>(One Port -                         | $\overline{CE}^*A^* < 0.2V$ and<br>$\overline{CE}^*B^* > VCC - 0.2V^{(5)}$  | COM'L        | S<br>L | 140<br>120          | 190<br>170 | 140<br>120            | 190<br>170 | 120<br>100            | 170<br>150 | mA                            |            |  |
|        | ĊMOS Level Inputs)  | $ \begin{array}{l} \text{VIN} > \text{VCC} - 0.2 \text{V } \text{or } \text{VIN} < 0.2 \text{V} \\ \text{Active Port Outputs Disabled} \\ f = \text{fMAX}^{(3)} \end{array} $ | MIL &<br>IND | S<br>L |                     |            | 140<br>120            | 220<br>200 | 120<br>100            | 190<br>170 |                               |            |  |

2746 tbl 07a

|  |  |  |              |          | 7133X45<br>7143X45<br>Com'l Only |            | 7133X55<br>7143X55<br>Com'l, Ind<br>& Military |            | 7133X70/90<br>7143X70/90<br>Com'l &<br>Military |            |      |
|--|--|--|--------------|----------|----------------------------------|------------|--|------------|---|------------|------|
| Symbol   | Parameter  | Test Condition   | Versi        | on       | Тур. <sup>(1)</sup>              | Мах.       | Typ. <sup>(1)</sup>                            | Мах.       | Typ. <sup>(1)</sup>                             | Max.       | Unit |
| ICC  | Dynamic Operating<br>Current   | $\overline{CE} = VIL$ , Outputs Disabled                                   | COM'L        | S<br>L   | 230<br>210                       | 290<br>250 | 230<br>210                                     | 285<br>250 | 230<br>210                                      | 280<br>250 | mA   |
| (Both Ports Active)  |  | MIL &<br>IND   | S<br>L       |          |                                  | 230<br>210 | 315<br>285                                     | 230<br>210 | 310<br>280                                      |            |      |
| ISB1 Standby Current<br>(Both Ports - TTL<br>Level Inputs) | Both Ports - TTL   | COM'L  | S<br>L       | 25<br>25 | 75<br>65                         | 25<br>25   | 70<br>60                                       | 25<br>25   | 70<br>60  | mA         |      |
|  |  | MIL &<br>IND   | S<br>L       |          |                                  | 25<br>25   | 80<br>70                                       | 25<br>25   | 75<br>65  |            |      |
| ISB2   | (One Port - TTL f=fMAX <sup>(3)</sup>  | f=fMAX <sup>(3)</sup>  | COM'L        | S<br>L   | 120<br>100                       | 190<br>170 | 120<br>100                                     | 180<br>160 | 120<br>100                                      | 180<br>160 | mA   |
|  | Level Inputs)  | Active Port Outputs Disabled   | MIL &<br>IND | S<br>L   |                                  |            | 120<br>100                                     | 210<br>190 | 120<br>100                                      | 200<br>180 |      |
| ISB3   | Full Standby Current<br>(Both Ports -  | Both Ports $\overline{CEL}$ and $\overline{CER} > Vcc - 0.2V$              | COM'L        | S<br>L   | 1.0<br>0.2                       | 15<br>4    | 1.0<br>0.2                                     | 15<br>4    | 1.0<br>0.2                                      | 15<br>4    | mA   |
| ČMOS Level Inputs)   | Level Inputs)<br>$ \begin{array}{l} \text{VIN} > \text{Vcc} - 0.2 \text{V or} \\ \text{VIN} < 0.2 \text{V}, \ \text{f} = 0^{(4)} \end{array} $ | MIL &<br>IND   | S<br>L       |          |                                  | 1.0<br>0.2 | 30<br>10                                       | 1.0<br>0.2 | 30<br>10  |            |      |
| ISB4   | (One Port - CE"B" >  | $\overline{CE}^*A^* < 0.2V$ and<br>$\overline{CE}^*B^* > VCC - 0.2V^{(5)}$ | COM'L        | S<br>L   | 120<br>100                       | 180<br>160 | 120<br>100                                     | 170<br>150 | 120<br>100                                      | 170<br>150 | mA   |
| ĊMOS Level Inputs)   | Active Port Outputs Disabled   | MIL &<br>IND   | S<br>L       |          |                                  | 120<br>100 | 200<br>180                                     | 120<br>100 | 190<br>170                                      |            |      |

#### NOTES:

1. Vcc = 5V, TA = +25°C for Typ., and are not production tested. Icccc = 180mA (typ.)

2. 'X' in part number indicates power rating (SA or LA)

3. At f = fMAX, address and control lines (except Output Enable) are cycling at the maximum frequency read cycle of 1/ trc, and using "AC Test Conditions" of input levels of GND to 3V.

4. f = 0 means no address or control lines change. Applies only to inputs at CMOS level standby.

5. Port "A" may be either left or right port. Port "B" is the opposite from port "A".



### Data Retention Characteristics (LA Version Only) VLC = 0.2V, VHC = VCC - 0.2V

|                     |                                      |  | 7133LA/7143LA                                |                    |     |      |           |
|---------------------|--------------------------------------|--|--|--------------------|-----|------|-----------|
| Symbol              | Parameter                            | Test Co                                    | Test Condition Min. Typ. <sup>(1)</sup> Max. |                    |     |      | Unit      |
| Vdr                 | Vcc for Data Retention               | Vcc = 2V                                   |  | 2.0                | _   |      | V         |
| ICCDR               | Data Retention Current               | CE ≥ VHC                                   | MIL. & IND.                                  | _                  | 100 | 4000 | μA        |
|                     |                                      | $V_{IN} \ge V_{HC} \text{ or } \le V_{LC}$ | COM'L.                                       | _                  | 100 | 1500 | ]         |
| tcdr <sup>(3)</sup> | Chip Deselect to Data Retention Time |  |  | 0                  | _   | _    | V         |
| tR <sup>(3)</sup>   | Operation Recovery Time              |  |  | trc <sup>(2)</sup> | _   | -    | V         |
|                     |                                      |  |  |                    |     | 2    | 746 tbl 0 |

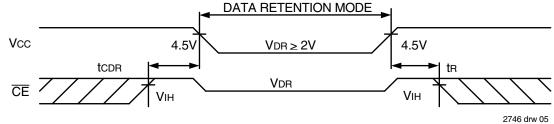
NOTES:

1. Vcc = 2V, TA =  $+25^{\circ}$ C, and are not production tested.

2. trc = Read Cycle Time

3. This parameter is guaranteed by device characterization but is not production tested.

## Data Retention Waveform



## AC Test Conditions

| Input Pulse Levels            | GND to 3.0V        |
|-------------------------------|--------------------|
| Input Rise/Fall Times         | 5ns Max.           |
| Input Timing Reference Levels | 1.5V               |
| Output Reference Levels       | 1.5V               |
| Output Load                   | Figures 1, 2 and 3 |
|                               |                    |

2746 tbl 09

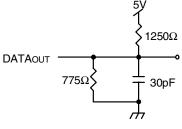
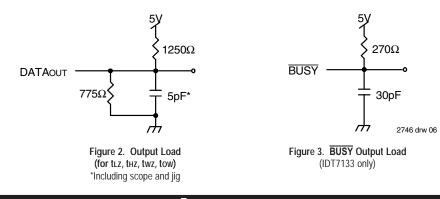


Figure 1. AC Output Test Load



Jun.16.21



## AC Electrical Characteristics Over the Operating Temperature and Supply Voltage<sup>(3)</sup>

|            |  |      | 7133X20<br>7143X20<br>Com'l Only |      | 7133X25<br>7143X25<br>Com'l & Ind |      | 7133X35<br>7143X35<br>Com'l<br>& Military |      |
|------------|--|------|----------------------------------|------|-----------------------------------|------|---|------|
| Symbol     | Parameter                                      | Min. | Мах.                             | Min. | Мах.                              | Min. | Max.                                      | Unit |
| READ CYCLE |  |      |                                  |      |                                   |      |   |      |
| trc        | Read Cycle Time                                | 20   |                                  | 25   |                                   | 35   |   | ns   |
| taa        | Address Access Time                            | _    | 20                               | _    | 25                                |      | 35  | ns   |
| tace       | Chip Enable Access Time                        | _    | 20                               |      | 25                                | _    | 35  | ns   |
| taoe       | Output Enable Access Time                      |      | 12                               |      | 15                                |      | 20  | ns   |
| toн        | Output Hold from Address Change                | 0    |                                  | 0    | _                                 | 0    | _   | ns   |
| tLZ        | Output Low-Z Time <sup>(1,2)</sup>             | 0    |                                  | 0    | _                                 | 0    |   | ns   |
| tHZ        | Output High-Z Time <sup>(1,2)</sup>            |      | 12                               |      | 15                                |      | 20  | ns   |
| tpu        | Chip Enable to Power Up Time <sup>(2)</sup>    | 0    |                                  | 0    |                                   | 0    |   | ns   |
| tpd        | Chip Disable to Power Down Time <sup>(2)</sup> |      | 20                               | _    | 50                                |      | 50  | ns   |

2746 tbl 10a

2746 tbl 10b

|            |  | 7133X45<br>7143X45<br>Com'l Only |      | 7133X55<br>7143X55<br>Com'l, Ind<br>& Military |      | 7133X70/90<br>7143X70/90<br>Com'l &<br>Military |       |      |
|------------|--|----------------------------------|------|--|------|---|-------|------|
| Symbol     | Parameter                                      | Min.                             | Max. | Min.   | Max. | Min.  | Max.  | Unit |
| READ CYCLE |  |                                  |      |  |      |   |       |      |
| tRC        | Read Cycle Time                                | 45                               |      | 55   |      | 70/90   |       | ns   |
| taa        | Address Access Time                            |                                  | 45   |  | 55   |   | 70/90 | ns   |
| tace       | Chip Enable Access Time                        |                                  | 45   |  | 55   |   | 70/90 | ns   |
| taoe       | Output Enable Access Time                      |                                  | 25   |  | 30   |   | 40/40 | ns   |
| tон        | Output Hold from Address Change                | 0                                |      | 0  |      | 0/0   |       | ns   |
| tLZ        | Output Low-Z Time <sup>(1,2)</sup>             | 0                                |      | 5  |      | 5/5   |       | ns   |
| tнz        | Output High-Z Time <sup>(1,2)</sup>            |                                  | 20   |  | 20   |   | 25/25 | ns   |
| tpu        | Chip Enable to Power Up Time <sup>(2)</sup>    | 0                                |      | 0  |      | 0/0   |       | ns   |
| tpd        | Chip Disable to Power Down Time <sup>(2)</sup> |                                  | 50   |  | 50   |   | 50/50 | ns   |

NOTES:

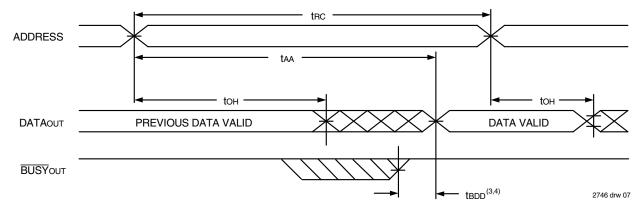
1. Transition is measured 0mV from Low or High-impedance voltage with load (Figure 2).

2. This parameter is guaranteed by device characterization, but is not production tested.

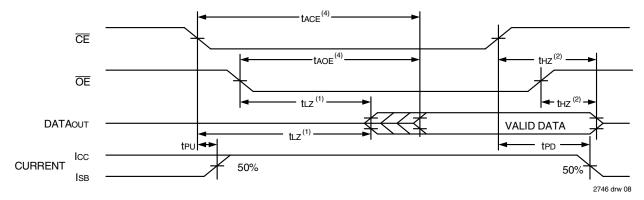
3. 'X' in part number indicates power rating (SA or LA).



## TIMING WAVEFORM OF READ CYCLE NO. 1, EITHER SIDE<sup>(5)</sup>



## TIMING WAVEFORM OF READ CYCLE NO. 2, EITHER SIDE<sup>(5)</sup>



NOTES:

1. Timing depends on which signal is asserted last,  $\overline{OE}$  or  $\overline{CE}$ . 2. Timing depends on which signal is de-asserted first,  $\overline{OE}$  or  $\overline{CE}$ .

- 3. tbdd delay is required only in a case where the opposite port is completing a write operation to the same address location. For simultaneous read operations, BUSY has no relationship to valid output data.
- 4. Start of valid data depends on which timing becomes effective last, tAOE, tACE, tAA, or tBDD.

5.  $R/\overline{W} = V_{H}$ , and the address is valid prior to or coincidental with  $\overline{CE}$  transition LOW.



## AC Electrical Characteristics Over the Operating Temperature and Supply Voltage<sup>(5)</sup>

|             |  | 7133X20<br>7143X20<br>Com'l Only |      | 7133X25<br>7143X25<br>Com'l & Ind |      | 7133X35<br>7143X35<br>Com'l<br>& Military |      |      |
|-------------|--|----------------------------------|------|-----------------------------------|------|---|------|------|
| Symbol      | Parameter  | Min.                             | Мах. | Min.                              | Мах. | Min.                                      | Max. | Unit |
| WRITE CYCLI | -<br>-   | -                                |      |                                   |      |   |      |      |
| twc         | Write Cycle Time <sup>(3)</sup>                    | 20                               | _    | 25                                |      | 35  | _    | ns   |
| tew         | Chip Enable to End-of-Write                        | 15                               | _    | 20                                |      | 25  | _    | ns   |
| taw         | Address Valid to End-of-Write                      | 15                               | _    | 20                                | —    | 25  | _    | ns   |
| tas         | Address Set-up Time                                | 0                                |      | 0                                 |      | 0   | _    | ns   |
| twp         | Write Pulse Width                                  | 15                               | _    | 20                                |      | 25  | _    | ns   |
| twr         | Write Recovery Time                                | 0                                | _    | 0                                 | —    | 0   | _    | ns   |
| tow         | Data Valid to End-of-Write                         | 15                               | _    | 15                                | _    | 20  | _    | ns   |
| tHZ         | Output High-Z Time <sup>(1,2)</sup>                | —                                | 12   |                                   | 15   |   | 20   | ns   |
| tDH         | Data Hold Time <sup>(4)</sup>                      | 0                                |      | 0                                 |      | 0   | _    | ns   |
| twz         | Write Enable to Output in High-Z <sup>(1,2)</sup>  | _                                | 12   |                                   | 15   |   | 20   | ns   |
| tow         | Output Active from End-of-Write <sup>(1,2,4)</sup> | 0                                |      | 0                                 |      | 0   | _    | ns   |

2746 tbl 11a

|            |  |      | 7133X45<br>7143X45<br>Com'l Only |      | 7133X55<br>7143X55<br>Com'l, Ind<br>& Military |       | 7133X70/90<br>7143X70/90<br>Com'l &<br>Military |              |
|------------|--|------|----------------------------------|------|--|-------|---|--------------|
| Symbol     | Parameter  | Min. | Max.                             | Min. | Мах.   | Min.  | Мах.  | Unit         |
| WRITE CYCL | E  |      |                                  |      |  |       |   |              |
| twc        | Write Cycle Time <sup>(3)</sup>                    | 45   |                                  | 55   |  | 70/90 | _   | ns           |
| tew        | Chip Enable to End-of-Write                        | 30   |                                  | 40   |  | 50/50 | _   | ns           |
| taw        | Address Valid to End-of-Write                      | 30   | _                                | 40   |  | 50/50 |   | ns           |
| tas        | Address Set-up Time                                | 0    |                                  | 0    |  | 0/0   | -   | ns           |
| twp        | Write Pulse Width                                  | 30   | _                                | 40   |  | 50/50 |   | ns           |
| twr        | Write Recovery Time                                | 0    |                                  | 0    | -  | 0/0   |   | ns           |
| tow        | Data Valid to End-of-Write                         | 20   | _                                | 25   |  | 30/30 | _   | ns           |
| tHZ        | Output High-Z Time <sup>(1,2)</sup>                |      | 20                               |      | 20   |       | 25/25   | ns           |
| tdн        | Data Hold Time <sup>(4)</sup>                      | 5    | _                                | 5    |  | 5/5   | _   | ns           |
| twz        | Write Enable to Output in High-Z <sup>(1,2)</sup>  |      | 20                               | _    | 20   | _     | 25/25   | ns           |
| tow        | Output Active from End-of-Write <sup>(1,2,4)</sup> | 5    |                                  | 5    |  | 5/5   | _   | ns           |
|            |  |      |                                  |      |  |       |   | 2746 tbl 11b |

NOTES:

1. Transition is measured 0mV from Low or High-impedance voltage from the Output Test Load (Figure 2).

2. This parameter is guaranteed by device characterization but not production tested.

3. For MASTER/SLAVE combination, twc = tBAA + twR + twP, since  $R/\overline{W}$  = VIL must occur after tBAA.

4. The specification for tDH must be met by the device supplying write data to the RAM under all operation conditions. Although tDH and tow values will vary over voltage and temperature, the actual tDH will always be smaller than the actual tow.

5. 'X' in part number indicates power rating (SA or LA).





## AC Electrical Characteristics Over the Operating Temperature and Supply Voltage<sup>(6)</sup>

|              |  | 714  | 7133X20<br>7143X20<br>Com'l Only |      | 7133X25<br>7143X25<br>Com'l & Ind |      | 7133X35<br>7143X35<br>Com'l<br>& Military |      |
|--------------|--|------|----------------------------------|------|-----------------------------------|------|---|------|
| Symbol       | Parameter  | Min. | Max.                             | Min. | Мах.                              | Min. | Max.                                      | Unit |
|              | G (For MASTER 71V33)                               |      |                                  |      |                                   |      |   |      |
| <b>t</b> BAA | BUSY Access Time from Address                      |      | 20                               |      | 20                                |      | 30  | ns   |
| tbda         | BUSY Disable Time from Address                     |      | 20                               | _    | 20                                |      | 30  | ns   |
| <b>t</b> BAC | BUSY Access Time from Chip Enable                  | _    | 20                               | _    | 20                                | _    | 25  | ns   |
| tBDC         | BUSY Disable Time from Chip Enable                 |      | 17                               |      | 20                                | _    | 25  | ns   |
| twdd         | Write Pulse to Data Delay <sup>(1)</sup>           |      | 40                               |      | 50                                | _    | 60  | ns   |
| todd         | Write Data Valid to Read Data Delay <sup>(1)</sup> |      | 30                               |      | 35                                |      | 45  | ns   |
| tbdd         | BUSY Disable to Valid Data <sup>(2)</sup>          |      | 25                               | -    | 30                                | -    | 35  | ns   |
| taps         | Arbitration Priority Set-up Time <sup>(3)</sup>    | 5    | _                                | 5    | _                                 | 5    |   | ns   |
| twн          | Write Hold After BUSY <sup>(5)</sup>               | 20   |                                  | 20   | _                                 | 25   |   | ns   |
| BUSY INPU    | f TIMING (For SLAVE 71V43)                         |      |                                  |      |                                   |      |   |      |
| twв          | BUSY Input to Write <sup>(4)</sup>                 | 0    | _                                | 0    |                                   | 0    |   | ns   |
| twн          | Write Hold After BUSY <sup>(5)</sup>               | 20   | _                                | 20   | -                                 | 25   |   | ns   |
| twdd         | Write Pulse to Data Delay <sup>(1)</sup>           |      | 40                               |      | 50                                |      | 60  | ns   |
| todd         | Write Data Valid to Read Data Delay <sup>(1)</sup> |      | 30                               |      | 35                                |      | 45  | ns   |

2746 tbl 12a

|              |  | 714  | 7143X45 7'<br>Com'l Only Co |      | 7133X55<br>7143X55<br>Com'l, Ind<br>& Military |       | 7133X70/90<br>7143X70/90<br>Com'l &<br>Military |      |
|--------------|--|------|-----------------------------|------|--|-------|---|------|
| Symbol       | Parameter  | Min. | Мах.                        | Min. | Max.   | Min.  | Мах.  | Unit |
| BUSY TIMI    | NG (For MASTER 71V33)                              |      |                             |      |  |       |   |      |
| <b>t</b> BAA | BUSY Access Time from Address                      |      | 40                          |      | 40   |       | 45/45   | ns   |
| tbda         | BUSY Disable Time from Address                     | —    | 40                          | _    | 40   |       | 45/45   | ns   |
| <b>t</b> BAC | BUSY Access Time from Chip Enable                  | —    | 30                          | _    | 35   |       | 35/35   | ns   |
| tBDC         | BUSY Disable Time from Chip Enable                 | —    | 25                          | _    | 30   | —     | 30/30   | ns   |
| twdd         | Write Pulse to Data Delay <sup>(1)</sup>           |      | 80                          | _    | 80   |       | 90/90   | ns   |
| todd         | Write Data Valid to Read Data Delay <sup>(1)</sup> |      | 55                          | _    | 55   |       | 70/70   | ns   |
| tBDD         | BUSY Disable to Valid Data <sup>(2)</sup>          | —    | 40                          | _    | 40   |       | 40/40   | ns   |
| taps         | Arbitration Priority Set-up Time <sup>(3)</sup>    | 5    | _                           | 5    |  | 5/5   |   | ns   |
| twн          | Write Hold After BUSY <sup>(5)</sup>               | 30   | _                           | 30   |  | 30/30 |   | ns   |
| BUSY INPL    | JT TIMING (For SLAVE 71V43)                        | -    |                             |      |  |       |   |      |
| twв          | BUSY Input to Write <sup>(4)</sup>                 | 0    | _                           | 0    |  | 0/0   |   | ns   |
| twн          | Write Hold After BUSY <sup>(5)</sup>               | 30   | _                           | 30   |  | 30/30 |   | ns   |
| twdd         | Write Pulse to Data Delay <sup>(1)</sup>           | —    | 80                          | _    | 80   |       | 90/90   | ns   |
| todd         | Write Data Valid to Read Data Delay <sup>(1)</sup> | _    | 55                          |      | 55   |       | 70/70   | ns   |

NOTES:

Port-to-port delay through RAM cells from writing port to reading port, refer to "Timing Waveform of Write with Port-to-Port Read and Busy". 1.

tBDD is calculated parameter and is greater of 0, twod - twp (actual) or tbbd - tbw (actual). 2.

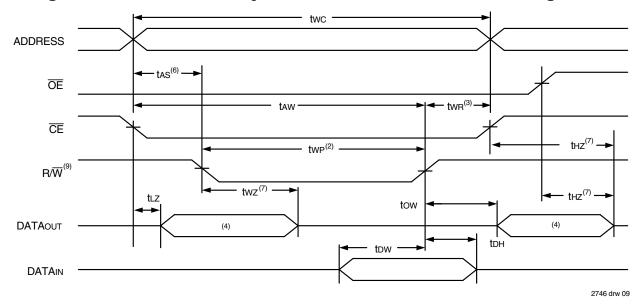
3. To ensure that the earlier of the two ports wins.

To ensure that the write cycle is inhibited on port "B" during contention on port "A". To ensure that the write cycle is completed on port "B" after contention on port "A". 'X' in part number indicates power rating (SA or LA). 4.

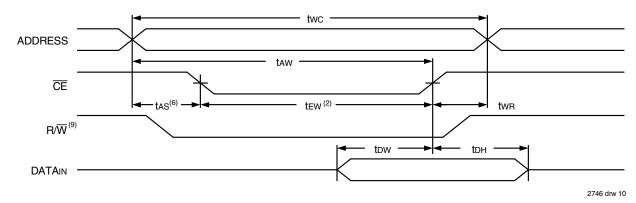
5. 6.



Timing Waveform of Write Cycle No. 1 (R/W Controlled Timing)<sup>(1,5,8)</sup>



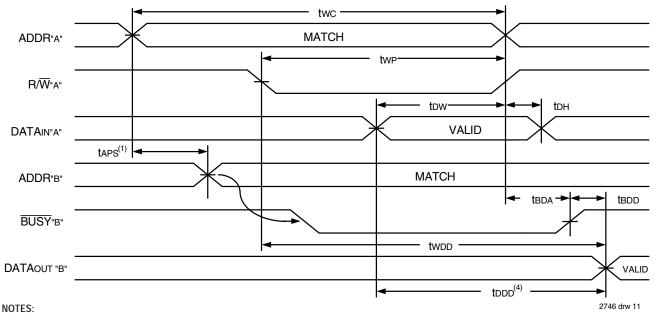
Write Cycle No. 2 (CE Controlled Timing)<sup>(1,5)</sup>



- 1.  $R/\overline{W}$  or  $\overline{CE}$  must be HIGH during all address transitions.
- 2. A write occurs during the overlap (tew or twp) of a  $\overline{CE} = V_{IL}$  and a  $R/\overline{W} = V_{IL}$ . 3. twr is measured from the earlier of  $\overline{CE}$  or  $R/\overline{W}$  going HIGH to the end of the write cycle.
- 4. During this period, the I/O pins are in the output state, and input signals must not be applied.
- 5. If the CE LOW transition occurs simultaneously with or after the RW LOW transition, the outputs remain in the High-impedance state.
- 6. Timing depends on which enable signal ( $\overline{CE}$  or  $\overline{R/W}$ ) is asserted last.
- Timing depends on which enable signal is de-asserted first,  $\overline{CE}$  or  $\overline{OE}$ . 7
- If  $\overline{OE}$  is LOW during a RW controlled write cycle, the write pulse width must be the larger of twp or (twz + tow) to allow the I/O drivers to turn off and data to be placed 8. on the bus for the required tow. If OE is HIGH during an RIW controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified twp.
- 9.  $\dot{R/W}$  for either upper or lower byte.



## Timing Waveform of Write with Port-to-Port Read and **BUSY**<sup>(1,2,3)</sup>

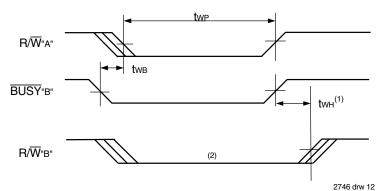


1. To ensure that the earlier of the two ports wins, taps is ignored for Slave (IDT7143).

- 2.  $\overline{CE}L = \overline{CE}R = VIL$
- 3.  $\overline{OE} = V_{IL}$  for the reading port.

4. All timing is the same for left and right ports. Port "A" may be either the left or right port. Port "B" is the port opposite from port "A".

## Timing Waveform of Write with **BUSY**<sup>(3)</sup>



#### NOTES:

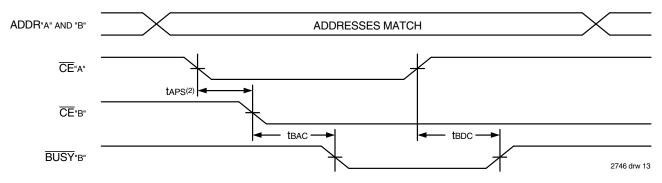
1. twn must be met for both BUSY input (IDT7143, slave) and output (IDT7133, master).

2. BUSY is asserted on port "B" blocking R/W"B", until BUSY"B" goes HIGH.

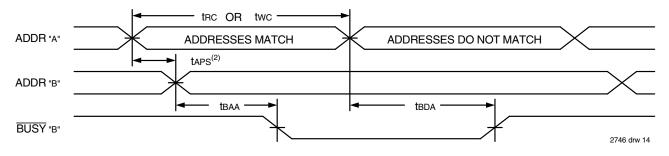
3. All timing is the same for left and right ports. Port "A" may be either left or right port. Port "B" is the opposite from port "A".



## Timing Waveform of **BUSY** Arbitration Controlled by **CE** Timing<sup>(1)</sup>



## Timing Waveform of **BUSY** Arbitration Controlled by Addresses<sup>(1)</sup>



- 1. All timing is the same for left and right ports. Port "A" may be either the left or right port. Port "B" is the port opposite from port "A".
- 2. If taps is not satisfied, the BUSY will be asserted on one side or the other, but there is no guarantee on which side BUSY will be asserted (IDT7133 only).



## **Functional Description**

The IDT7133/43 provides two ports with separate control, address and I/O pins that permit independent access for reads or writes to any location in memory. The IDT7133/43 has an automatic power down feature controlled by CE. The CE controls on-chip power down circuitry that permits the respective port to go into a standby mode when not selected (CE HIGH). When a port is enabled, access to the entire memory array is permitted. Non-contention READ/WRITE conditions are illustrated in Truth Table 1.

## **Busy Logic**

Busy Logic provides a hardware indication that both ports of the RAM have accessed the same location at the same time. It also allows one of the two accesses to proceed and signals the other side that the RAM is "busy". The BUSY pin can then be used to stall the access until the operation on the other side is completed. If a write operation has been attempted from the side that receives a BUSY indication, the write signal is gated internally to prevent the write from proceeding.

The use of BUSY logic is not required or desirable for all applications. In some cases it may be useful to logically OR the BUSY outputs together and use any BUSY indication as an interrupt source to flag the event of an illegal or illogical operation. If the write inhibit function of BUSY logic is not desirable, the BUSY logic can be disabled by using the IDT7143 (SLAVE). In the IDT7143, the BUSY pin operates solely as a write inhibit input pin. Normal operation can be programmed by tying the BUSY pins HIGH. If desired, unintended write operations can be prevented to a port by tying the BUSY pin for that port LOW. The BUSY outputs on the IDT 7133 RAM are open drain and require pullup resistors.

## Width Expansion with Busy Logic Master/Slave Arrays

When expanding an IDT7133/43 RAM array in width while using BUSY logic, one master part is used to decide which side of the RAM array will receive a BUSY indication, and to output that indication. Any number of slaves to be addressed in the same address range as the master, use the BUSY signal as a write inhibit signal. Thus on the IDT7133 RAM the BUSY pin is an output and on the IDT7143 RAM, the BUSY pin is an input (see Figure 3).

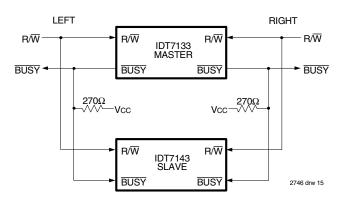


Figure 4. Busy and chip enable routing for both width and depth expansion with the IDT7133 (MASTER) and the IDT7143 (SLAVE).

Expanding the data bus width to 32 bits or more in a Dual-Port RAM system implies that several chips will be active at the same time. If each chip includes a hardware arbitrator, and the addresses for each chip arrive at the same time, it is possible that one will activate its BUSYL while another activates its BUSYR signal. Both sides are now BUSY and the CPUs will await indefinitely for their port to become free.

To avoid the "Busy Lock-Out" problem, IDT has developed a MASTER/SLAVE approach where only one hardware arbitrator, in the MASTER, is used. The SLAVE has **BUSY** inputs which allow an interface to the MASTER with no external components and with a speed advantage over other systems.

When expanding Dual-Port RAMs in width, the writing of the SLAVE RAMs must be delayed until after the BUSY input has settled. Otherwise, the SLAVE chip may begin a write cycle during a contention situation. Conversely, the write pulse must extend a hold time past BUSY to ensure that a write cycle takes place after the contention is resolved. This timing is inherent in all Dual-Port memory systems where more than one chip is active at the same time.

The write pulse to the SLAVE should be delayed by the maximum arbitration time of the MASTER. If, then, a contention occurs, the write to the SLAVE will be inhibited due to **BUSY** from the MASTER.

Truth Table I – Non-Contention Read/Write Control<sup>(4)</sup>

| LEFT OR RIGHT PORT <sup>(1)</sup> |       |    |    |         |         |  |
|-----------------------------------|-------|----|----|---------|---------|--|
| R/WLB                             | R/WUB | ĒĒ | ŌĒ | I/O0-7  | I/O8-15 | Function   |
| Х                                 | Х     | Н  | Х  | Z       | Z       | Port Disabled and in Power Down Mode, ISB2, ISB4   |
| Х                                 | Х     | Н  | Х  | Z       | Z       | CER = CEL = VIH, Power Down Mode, ISB1 or ISB3   |
| L                                 | L     | L  | Х  | DATAIN  | DATAIN  | Data on Lower Byte and Upper Byte Written into $Memory^{(\!2\!)}$  |
| L                                 | Н     | L  | L  | DATAIN  | DATAout | Data on Lower Byte Written into $\text{Memory}^{(2)},$ Data in Memory Output on Upper $\text{Byte}^{(3)}$  |
| Н                                 | L     | L  | L  | DATAOUT | DATAIN  | Data in Memory Output on Lower Byte $^{(3)},$ Data on Upper Byte Written into ${\rm Memory}^{(\!\!\!\!2)}$ |
| L                                 | Н     | L  | Н  | DATAIN  | Z       | Data on Lower Byte Written into Memory <sup>(2)</sup>  |
| Н                                 | L     | L  | Н  | Z       | DATAIN  | Data on Upper Byte Written into Memory <sup>(2)</sup>  |
| Н                                 | Н     | L  | L  | DATAOUT | DATAOUT | Data in Memory Output on Lower Byte and Upper Byte   |
| Н                                 | Н     | L  | Н  | Z       | Z       | High Impedance Outputs   |

#### NOTES:

1. Aol - A10L≠Aor - A10r

2. If  $\overline{\text{BUSY}}$  = LOW, data is not written.

3. If **BUSY** = LOW, data may not be valid, see twod and todd timing.

4. "H" = HIGH, "L" = LOW, "X" = Don't Care, "Z" = High-Impedance, "LB" = Lower Byte, "UB" = Upper Byte

## Truth Table II — Address **BUSY** Arbitration

|     | In          | puts                 | Out                   | puts                             |                              |
|-----|-------------|----------------------|-----------------------|----------------------------------|------------------------------|
| ĒĒ∟ | <b>Č</b> ER | Aol-A1ol<br>Aor-A1or | BUS YL <sup>(1)</sup> | BUSY <sub>R</sub> <sup>(1)</sup> | Function                     |
| Х   | Х           | NO MATCH             | Н                     | Н                                | Normal                       |
| Н   | Х           | MATCH                | Н                     | Н                                | Normal                       |
| Х   | Н           | MATCH                | Н                     | Н                                | Normal                       |
| L   | L           | MATCH                | (2)                   | (2)                              | Write Inhibit <sup>(3)</sup> |
|     |             |                      |                       |                                  | 2746 tbl 14                  |

#### NOTES:

- Pins BUSYL and BUSYR are both outputs on the IDT7133 (MASTER). Both are inputs on the IDT7143 (SLAVE). On Slaves the BUSY input internally inhibits writes.
- "L" if the inputs to the opposite port were stable prior to the address and enable inputs of this port. "H" if the inputs to the opposite port became stable after the address and enable inputs of this port. If tAPS is not met, either BUSYL or BUSYR = ViL will result BUSYL and BUSYR outputs can not be LOW simultaneously.
- Writes to the left port are internally ignored when BUSYL outputs are driving LOW regardless of actual logic level on the pin. Writes to the right port are internally ignored when BUSYR outputs are driving LOW regardless of actual logic level on the pin.

Military, Industrial and Commercial Temperature Ranges

#### 2746 tbl 13

#### 7133SA/LA, 7143SA/LA High-Speed 2K x 16 Dual-Port RAM Military, Industrial and Commercial Temperature Ranges Ordering Information 999 XXXXX \_\_\_\_A А А A А Device Power Package Process/ Speed Temperature Range Туре Blank Tube or Tray 8 Tape and Reel Commercial (0°C to +70°C) Industrial (-40°C to +85°C) Military (-55°C to +125°C) Compliant to MIL-PRF-38535 QML Blank [<sup>(1)</sup> В G<sup>(2)</sup> Green 68-pin PLCC (PLG68) 68-pin PGA (GU68) 68-pin Flatpack (FP68) 100-pin TQFP (PNG100) J G F PF Commercial Only Commercial & Industrial Commercial & Military Commercial & Military Commercial & Military Commercial & Military 20 25 35 45 55 70 90 Speed in nanoseconds

#### NOTES:

1. Contact your local sales office for industrial temp. range for other speeds, packages and powers.

 Green parts available. For specific speeds, packages and powers contact your local sales office. LEAD FINISH (SnPb) parts are Obsolete excluding PGA and Flatpack. Product Discontinuation Notice - PDN# SP-17-02 Note that information regarding recently obsoleted parts are included in this datasheet for customer convenience.

## Orderable Part Information

| Speed<br>(ns) | Orderable Part ID | Pkg.<br>Code | Pkg.<br>Type | Temp.<br>Grade |
|---------------|-------------------|--------------|--------------|----------------|
| 20            | 7133LA20G         | GU68         | PGA          | С              |
|               | 7133LA20JG        | PLG68        | PLCC         | С              |
|               | 7133LA20JG8       | PLG68        | PLCC         | С              |
|               | 7133LA20PFG       | PNG100       | TQFP         | С              |
|               | 7133LA20PFG8      | PNG100       | TQFP         | С              |
| 25            | 7133LA25G         | GU68         | PGA          | С              |
|               | 7133LA25JGI       | PLG68        | PLCC         | I              |
|               | 7133LA25JGI8      | PLG68        | PLCC         | I              |
|               | 7133LA25PFGI      | PNG100       | TQFP         | I              |
|               | 7133LA25PFGI8     | PNG100       | TQFP         | I              |
| 35            | 7133LA35FB        | FP68         | FPACK        | М              |
|               | 7133LA35G         | GU68         | PGA          | С              |
|               | 7133LA35GB        | GU68         | PGA          | М              |
| 45            | 7133LA45G         | GU68         | PGA          | С              |
| 55            | 7133LA55FB        | FP68         | FPACK        | М              |
|               | 7133LA55G         | GU68         | PGA          | С              |
|               | 7133LA55GB        | GU68         | PGA          | М              |
| 70            | 7133LA70G         | GU68         | PGA          | С              |
|               | 7133LA70GB        | GU68         | PGA          | М              |
| 90            | 7133LA90G         | GU68         | PGA          | С              |
|               | 7133LA90GB        | GU68         | PGA          | М              |

| Speed<br>(ns) | Orderable Part ID | Pkg.<br>Code | Pkg.<br>Type | Temp.<br>Grade |
|---------------|-------------------|--------------|--------------|----------------|
| 20            | 7133SA20G         | GU68         | PGA          | С              |
| 25            | 7133SA25G         | GU68         | PGA          | С              |
| 35            | 7133SA35FB        | FP68         | FPACK        | М              |
|               | 7133SA35G         | GU68         | PGA          | С              |
|               | 7133SA35GB        | GU68         | PGA          | М              |
|               | 7133SA35PFG       | PNG100       | TQFP         | С              |
|               | 7133SA35PFG8      | PNG100       | TQFP         | С              |
| 45            | 7133SA45G         | GU68         | PGA          | С              |
| 55            | 7133SA55FB        | FP68         | FPACK        | М              |
|               | 7133SA55G         | GU68         | PGA          | С              |
|               | 7133SA55GB        | GU68         | PGA          | М              |
| 70            | 7133SA70G         | GU68         | PGA          | С              |
|               | 7133SA70GB        | GU68         | PGA          | М              |
| 90            | 7133SA90G         | GU68         | PGA          | С              |
|               | 7133SA90GB        | GU68         | PGA          | М              |

32K (2K x 16-Bit) MASTER Dual-Port RAM 32K (2K x 16-Bit) SLAVE Dual-Port RAM

2746 drw 16

Low Power Standard Power

LA SA

7133 7143



Military, Industrial and Commercial Temperature Ranges

| Speed<br>(ns) | Orderable Part ID | Pkg.<br>Code | Pkg.<br>Type | Temp.<br>Grade |
|---------------|-------------------|--------------|--------------|----------------|
| 20            | 7143LA20G         | GU68         | PGA          | С              |
|               | 7143LA20JG        | PLG68        | PLCC         | С              |
|               | 7143LA20JG8       | PLG68        | PLCC         | С              |
| 25            | 7143LA25G         | GU68         | PGA          | С              |
| 35            | 7143LA35FB        | FP68         | FPACK        | М              |
|               | 7143LA35G         | GU68         | PGA          | С              |
|               | 7143LA35GB        | GU68         | PGA          | М              |
| 55            | 7143LA55G         | GU68         | PGA          | С              |
|               | 7143LA55GB        | GU68         | PGA          | М              |
| 70            | 7143LA70GB        | GU68         | PGA          | М              |
| 90            | 7143LA90GB        | GU68         | PGA          | М              |

| Speed<br>(ns) | Orderable Part ID | Pkg.<br>Code | Pkg.<br>Type | Temp.<br>Grade |
|---------------|-------------------|--------------|--------------|----------------|
| 20            | 7143SA20G         | GU68         | PGA          | С              |
| 25            | 7143SA25G         | GU68         | PGA          | С              |
| 35            | 7143SA35FB        | FP68         | FPACK        | М              |
|               | 7143SA35G         | GU68         | PGA          | С              |
|               | 7143SA35GB        | GU68         | PGA          | М              |
| 55            | 7143SA55G         | GU68         | PGA          | С              |
|               | 7143SA55GB        | GU68         | PGA          | М              |
| 70            | 7143SA70GB        | GU68         | PGA          | М              |
| 90            | 7143SA90GB        | GU68         | PGA          | М              |

## Orderable Part Information (con't)

## Datasheet Document History

| 12/18/98: |                     | Initiated datasheet document history  |
|-----------|---------------------|---|
|           |                     | Converted to new format   |
|           |                     | Cosmetic and typographical corrections  |
|           |                     | Added additional notes to pin configurations  |
|           | Page 2              | Corrected PN100 pinout  |
| 02/17/99: |                     | Corrected PF ordering code  |
| 030/9/99: |                     | Cosmetic and typographical corrections  |
| 06/09/99: |                     | Changed drawing format  |
| 10/01/99: |                     | Added Industrial Temperature Ranges and removed corresponding notes                                   |
| 11/10/99: |                     | Replaced IDT logo   |
| 04/01/00: |                     | Changed ±500mV to 0mV in notes  |
|           | Page 2              | Fixed overbar in pinout   |
| 06/26/00: | Page 4              | Increased storage temperature parameters  |
|           |                     | Clarified TA parameter  |
|           | Page 5              | DC Electrical parameters-changed wording from "open" to "disabled"                                    |
| 01/31/06: | Page 1              | Added green availability to features  |
|           | Page 16             | Added green indicator for ordering information  |
| 10/21/08: | Page 16             | Removed "IDT" from orderable part number  |
| 01/16/13: | Page 1, 5, 7, 9 &10 | Removed Military 25ns & 45ns & Industrial 35ns speed grades from Features and from the headers of the |
|           |                     | MIL & IND of the DC Chars and AC Chars tables to indicate this change                                 |
|           | Page 5              | Removed the Typ & Max values for the MIL & IND temp range from the 7133x45 and 7143x45 speed grade    |
|           |                     | offering from the DC Chars tables to indicate this change, see table 07b                              |
|           | Page 4              | Removed annotation for footnote 3 in the Absolute Maximum Ratings table                               |
|           | Page 8 & 9          | Typo/correction   |
|           | Page 16             | Added T& R indicator to and removed Military 25ns & 45ns & Industrial 35ns speed                      |
|           |                     | grades from the ordering information  |
|           |                     | Product Discontinuation Notice - PDN# SP-17-02  |
|           |                     | Last time buy expires June 15, 2018   |
| 08/13/19: |                     | Page 1 & 16 Deleted obsolete Industrial speed 55ns  |
|           |                     | Page 2 Rotated PLG68 PLCC and PNG100 TQFP pin configurations to accurately                            |
|           |                     | reflect pin 1 orientation   |
|           |                     | Page 16 Added Orderable Part Information  |
| 06/16/21: |                     | Pages 1-19 Rebranded as Renesas datasheet   |
|           |                     | Page 2 Rotated FP68 Flatpack pin configuration to accurately reflect pin 1 orientation                |



#### IMPORTANT NOTICE AND DISCLAIMER

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers skilled in the art designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only for development of an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising out of your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Rev.1.0 Mar 2020)

#### **Corporate Headquarters**

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

### **Trademarks**

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

#### **Contact Information**

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit: www.renesas.com/contact/